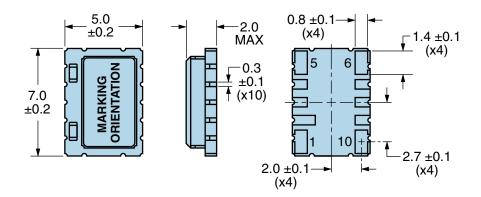


ELECTRICAL SPECIFICATIONS		
Nominal Frequency	27.000MHz	
Frequency Stability vs. Frequency Tolerance	±1.0ppm Maximum (Measured at 25°C ±2°C, Vdd=3.3Vdc, Vc=1.5Vdc)	
Frequency Stability	±1.0ppm Maximum	
Frequency Stability vs. Input Voltage	±0.2ppm Maximum (Vdd ±5%)	
Frequency Stability vs. Aging	±1ppm/Year Maximum (at 25°C)	
Frequency Stability vs. Load	±0.2ppm Maximum (±1kOhm//±1pF)	
Operating Temperature Range	0°C to +50°C	
Supply Voltage	3.3Vdc ±5%	
Input Current	2.5mA Maximum	
Output Voltage	0.8Vp-p Clipped Sinewave Minimum	
Load Drive Capability	10kOhms//10pF	
Output Logic Type	Clipped Sinewave	
Control Voltage	None (No Connect on Pin 1)	
Phase Noise	-80dBc/Hz at 10Hz offset, -115dBc/Hz at 100Hz offset, -135dBc/Hz at 1kHz offset, -145dBc/Hz at 10kHz offset, -145dBc/Hz at 100kHz offset (Typical Values, at 12.800MHz)	
Start Up Time	5mSec Maximum	
Storage Temperature Range	-55°C to +125°C	

ENVIRONMENTAL & MECHANICAL SPECIFICATIONS		
Fine Leak Test	MIL-STD-883, Method 1014 Condition A	
Gross Leak Test	MIL-STD-883, Method 1014 Condition C	
Mechanical Shock	MIL-STD-202, Method 213 Condition C	
Resistance to Soldering Heat	MIL-STD-202, Method 210	
Resistance to Solvents	MIL-STD-202, Method 215	
Solderability	MIL-STD-883, Method 2003	
Temperature Cycling	MIL-STD-883, Method 1010	
Vibration	MIL-STD-883, Method 2007 Condition A	



#### **MECHANICAL DIMENSIONS (all dimensions in millimeters)**

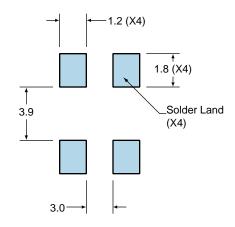


PIN	CONNECTION
1	No Connect
2	Do Not Connect
3	Do Not Connect
4	Do Not Connect
5	Case/Ground
6	Output
7	Do Not Connect
8	Do Not Connect
9	Do Not Connect
10	Supply Voltage

LINE	MARKING
1	<b>E27.000</b> <i>E=Ecliptek</i>
2	XXYZZ  XX=Ecliptek Manufacturing Code  Y=Last Digit of the Year  ZZ=Week of the Year

#### **Suggested Solder Pad Layout**

All Dimensions in Millimeters

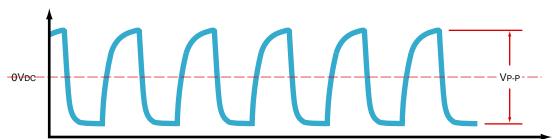


All Tolerances are ±0.1



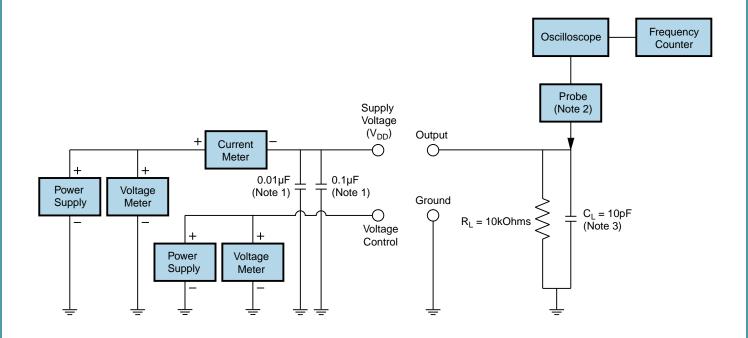
#### **OUTPUT WAVEFORM**

**CLOCK OUTPUT** 





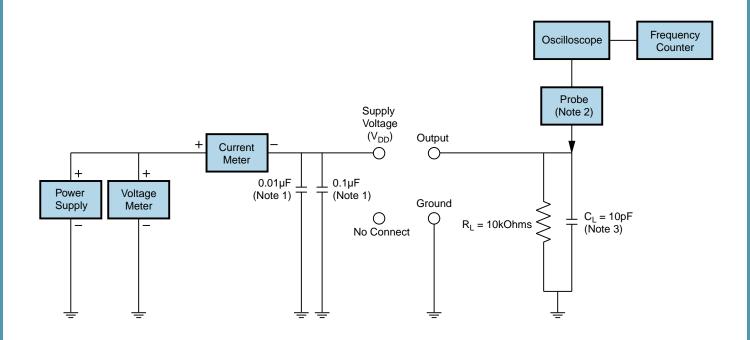
#### **Test Circuit for Voltage Control Option**



- Note 1: An external  $0.1\mu F$  low frequency tantalum bypass capacitor in parallel with a  $0.01\mu F$  high frequency ceramic bypass capacitor close to the package ground and  $V_{DD}$  pin is required.
- Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.
- Note 3: Capacitance value  $\dot{C}_L$  includes sum of all probe and fixture capacitance.



#### **Test Circuit for No Connect Option**

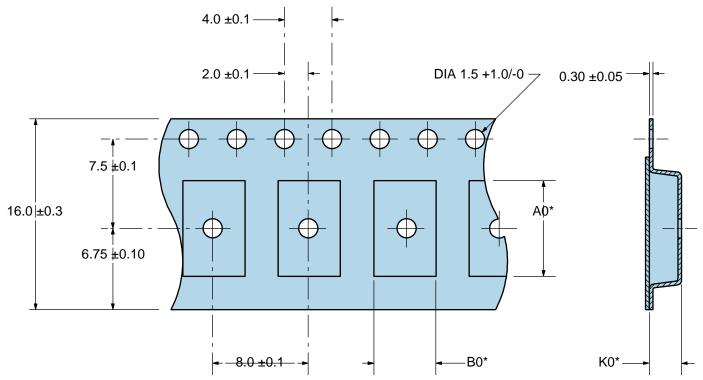


- Note 1: An external 0.1µF low frequency tantalum bypass capacitor in parallel with a 0.01µF high frequency ceramic bypass capacitor close to the package ground and V<sub>DD</sub> pin is required.
- Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.
- Note 3: Capacitance value  $\dot{C}_L$  includes sum of all probe and fixture capacitance.

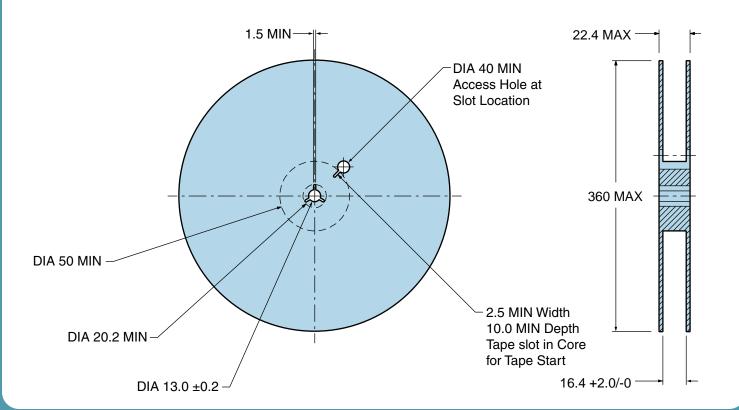


# **Tape & Reel Dimensions**

Quantity Per Reel: 1,000 units

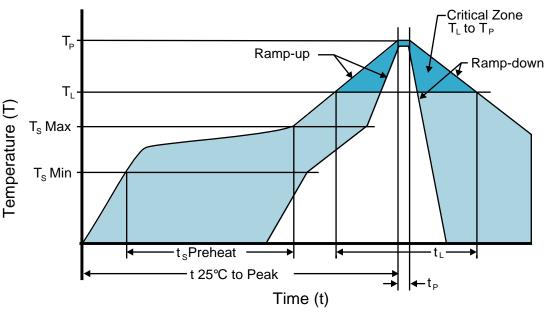


\*Compliant to EIA 481





### **Recommended Solder Reflow Methods**



#### Low Temperature Infrared/Convection 220°C

Ts MAX to T∟ (Ramp-up Rate)	5°C/second Maximum
Preheat	
- Temperature Minimum (Ts MIN)	N/A
- Temperature Typical (Ts TYP)	150°C
- Temperature Maximum (Ts MAX)	N/A
- Time (ts MIN)	60 - 120 Seconds
Ramp-up Rate (T∟ to T <sub>P</sub> )	5°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	150°C
- Time (t∟)	200 Seconds Maximum
Peak Temperature (T <sub>P</sub> )	220°C Maximum
Target Peak Temperature (T <sub>P</sub> Target)	220°C Maximum 1 Time / 215°C Maximum 1 Time
Time within 5°C of actual peak (tp)	15 seconds Maximum 1 Time / 80 seconds Maximum 1 Time
Ramp-down Rate	5°C/second Maximum
Time 25°C to Peak Temperature (t)	N/A
Moisture Sensitivity Level	Level 1

#### **Low Temperature Manual Soldering**

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

#### **High Temperature Manual Soldering**

260°C Maximum for 5 seconds Maximum, 2 times Maximum.